NSN 5961-00-241-3646

Transistor - Page 1 of 1

No Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-00-241-3646 **Inclosure Material:** Plastic **Overall Length:** Between 0.170 inches and 0.210 inches **Terminal Length:** 0.500 inches **Overall Height:** Between 0.125 inches and 0.165 inches **Overall Width:** Between 0.175 inches and 0.205 inches **Internal Configuration:** Field effect Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-92 **Mounting Method: Terminal Terminal Circle Diameter:** 0.100 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 50.0 drain to gate voltage and 50.0 drain to source voltage **Current Rating Per Characteristic:** 10.00 milliamperes gate current **Power Rating Per Characteristic:** 300.0 milliwatts total device dissipation **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius junction **Test Data Document:** 80009-151-1005-00 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:**